

BSC010NE2LSI

Request a Quote

BSC010NE2LSI Information

		BSC010NE2LSI Infineon Technologies Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single	
EFFE P	Description Package	MOSFET N-CH 25V 38A TDSON-8 8-PowerTDFN	
For Reference Only		For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com	

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



BSC010NE2LSI Specifications

Manufacturer Part Number	BSC010NE2LSI
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-PowerTDFN
Series	OptiMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	25V
Current - Continuous Drain (Id) @ 25°C	38A (Ta), 100A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	59nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	4200pF @ 12V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	2.5W (Ta), 96W (Tc)
Rds On (Max) @ Id, Vgs	1.05 mOhm @ 30A, 10V
Operating Temperature	-
Mounting Type	Surface Mount
Supplier Device Package	PG-TDSON-8
Package / Case	8-PowerTDFN
	Report errors?

BSC010NE2LSI Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE SUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

BSC010NE2LSI Payment Methods



BSC010NE2LSI Shipping Methods



If you have any question about BSC010NE2LSI, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com